## LOUDSPEAKER \& HEADSET DRIVER WITH VOLUME CONTROL

- OPERATING FROM $\mathrm{V}_{\mathrm{cc}}=3.0 \mathrm{~V}$ to 5.0 V
$\square$ SPEAKER: Mono, THD+N @ 1 kHz is $1 \%$ Max @ 1 W into $8 \Omega$ BTL
- HEADSET: Stereo, THD+N @ 1 kHz is $0.5 \%$ Max. @ 85 mW into $32 \Omega$ BTL
- VOLUME CONTROL: 32-step digital volume control
- OUTPUT MODE: Eight different selections
- Ultra low pop-and-click
- Low Shutdown Current ( $0.1 \mu \mathrm{~A}$, typ.)
- Thermal Shutdown Protection
- FLIP-CHIP Package 18 X $300 \mu \mathrm{~m}$ Bumps
- TS4855E IJT Lead-Free option available


## DESCRIPTION

The TS4855 is a complete low power audio amplifier solution targeted at mobile phones. It integrates, into an extremely compact flip-chip package, an audio amplifier, a speaker driver, and a headset driver.

The Audio Power Amplifier can deliver 1.1 W (typ.) of continuous RMS output power into an $8 \Omega$ speaker with a $1 \%$ THD+N value. To the headset driver, the amplifier can deliver 85 mW (typ.) per channel of continuous average power into stereo $32 \Omega$ bridged-tied load with $0.5 \%$ THD+N @ 5 V .

This device features a 32-step digital volume control and 8 different output selections. The digital volume and output modes are controlled through a three-digit SPI interface bus.

## APPLICATIONS

- Mobile Phones

ORDER CODE

| Part Number | Temperature | Package |
| :--- | :---: | :---: |
|  |  | Jange |

PIN CONNECTIONS (top view)


## 1 APPLICATION INFORMATION FOR A TYPICAL APPLICATION



External component descriptions

| Component | Functional Description |
| :---: | :--- |
| $\mathbf{C}_{\text {in }}$ | This is the input coupling capacitor. It blocks the DC voltage at, and couples the input signal to the <br> amplifier's input terminals. Cin also creates a highpass filter with the internal input impedance Zin at <br> Fc $=1 /(2 \pi \times$ Zin $\times$ Cin $)$. |
| $\mathbf{C}_{\mathbf{s}}$ | This is the Supply Bypass capacitor. It provides power supply filtering. |
| $\mathbf{C}_{\mathbf{B}}$ | This is the Bypass pin capacitor. It provides half-supply filtering. |

## 2 SPI BUS INTERFACE

### 2.1 Pin Descriptions

| Pin |  |
| :---: | :--- |
| DATA | This is the serial data input pin |
| CLK | This is the clock input pin |
| ENB | This is the SPI enable pin active at high level |

### 2.2 SPI Operation Description

The serial data bits are organized into a field containing 8 bits of data as shown in Table 1. The DATA 0 to DATA 2 bits determine the output mode of the TS4855 as shown in Table 2. The DATA 3 to DATA 7 bits determine the gain level setting as illustrated by Table 3. For each SPI transfer, the data bits are written to the DATA pin with the least significant bit (LSB) first. All serial data are sampled at the rising edge of the CLK signal. Once all the data bits have been sampled, ENB transitions from logic-high to logic low to complete the SPI sequence. All 8 bits must be received before any data latch can occur. Any excess CLK and DATA transitions will be ignored after the height rising clock edge has occurred. For any data sequence longer than 8 bits, only the
first 8 bits will get loaded into the shift register and the rest of the bits will be disregarded.

Table 1: Bit Allocation

|  | DATA | MODES |
| :--- | :---: | :---: |
| LSB | DATA 0 | Mode 1 |
|  | DATA 1 | Mode 2 |
|  | DATA 2 | Mode 3 |
|  | DATA 3 | gain 1 |
|  | DATA 4 | gain 2 |
|  | DATA 5 | gain 3 |
|  | DATA 6 | gain 4 |
| MSB | DATA 7 | gain 5 |

Table 2: Output Mode Selection

| Output Mode \# | DATA 2 | DATA 1 | DATA 0 | $\mathbf{S P K R}_{\text {out }}$ | $\mathrm{R}_{\text {out }}$ | Lout |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 0 | 0 | 0 | 0 | SD | SD | SD |
| 1 | 0 | 0 | 1 | +12 dBxP IHF | SD | SD |
| 2 | 0 | 1 | 0 | MUTE | G1xP ${ }_{\text {HS }}$ | G1xP ${ }_{\text {HS }}$ |
| 3 | 0 | 1 | 1 | +12 dBxP IHF | $\mathrm{G1xP}_{\text {HS }}$ | G1xP ${ }_{\text {HS }}$ |
| 4 | 1 | 0 | 0 | MUTE | $\mathrm{G} 2 \times \mathrm{R}_{\text {in }}$ | G2xL ${ }_{\text {in }}$ |
| 5 | 1 | 0 | 1 | +12dBxP ${ }_{\text {IHF }}$ | $\mathrm{G} 2 \times \mathrm{R}_{\text {in }}$ | $\mathrm{G} 2 \times \mathrm{L}_{\text {in }}$ |
| 6 | 1 | 1 | 0 | MUTE | $\begin{gathered} {\mathrm{G} 1 \times \mathrm{P}_{\mathrm{HS}^{+}}}_{\mathrm{G} 2 \times \mathrm{R}_{\text {in }}} \end{gathered}$ | $\begin{gathered} {\mathrm{G} 1 \times \mathrm{P}_{\mathrm{HS}^{+}}}_{\mathrm{G} 2 \mathrm{~L}_{\text {in }}} \end{gathered}$ |
| 7 | 1 | 1 | 1 | +12 dBxP IHF | $\begin{gathered} {\mathrm{G} 1 \times \mathrm{P}_{\mathrm{HS}}} \\ {\mathrm{G} 2 \times \mathrm{R}_{\mathrm{in}}}^{\text {an }} \end{gathered}$ | $\begin{gathered} {\mathrm{G} 1 \times \mathrm{P}_{\mathrm{HS}}}^{\mathrm{G} 2 \mathrm{~L} \mathrm{~L}_{\text {in }}} \end{gathered}$ |

(SD = Shut Down Mode, $\mathrm{P}_{\text {HS }}=$ Non Filtered Phone In HS, $\mathrm{P}_{\mathrm{IHF}}=$ External High Pass Filtered Phone In IHF)

Table 3: Gain Control Settings

| G2: Gain (dB) | G1: Gain (dB) | DATA 7 | DATA 6 | DATA 5 | DATA 4 | DATA 3 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| -34.5 | -40.5 | 0 | 0 | 0 | 0 | 0 |
| -33.0 | -39.0 | 0 | 0 | 0 | 0 | 1 |
| -31.5 | -37.5 | 0 | 0 | 0 | 1 | 0 |
| -30.0 | -36.0 | 0 | 0 | 0 | 1 | 1 |
| -28.5 | -34.5 | 0 | 0 | 1 | 0 | 0 |
| -27.0 | -33.0 | 0 | 0 | 1 | 0 | 1 |
| -25.5 | -31.5 | 0 | 0 | 1 | 1 | 0 |
| -24.0 | -30.0 | 0 | 0 | 1 | 1 | 1 |
| -22.5 | -28.5 | 0 | 1 | 0 | 0 | 0 |
| -21.0 | -27.0 | 0 | 1 | 0 | 0 | 1 |
| -19.5 | -25.5 | 0 | 1 | 0 | 1 | 0 |
| -18.0 | -24.0 | 0 | 1 | 0 | 1 | 1 |
| -16.5 | -22.5 | 0 | 1 | 1 | 0 | 0 |
| -15.0 | -21.0 | 0 | 1 | 1 | 0 | 1 |
| -13.5 | -19.5 | 0 | 1 | 1 | 1 | 0 |
| -12.0 | -18.0 | 0 | 1 | 1 | 1 | 1 |
| -10.5 | -16.5 | 1 | 0 | 0 | 0 | 0 |
| -9.0 | -15.0 | 1 | 0 | 0 | 0 | 1 |
| -7.5 | -13.5 | 1 | 0 | 0 | 1 | 0 |
| -6.0 | -12.0 | 1 | 0 | 0 | 1 | 1 |
| -4.5 | -10.5 | 1 | 0 | 1 | 0 | 0 |
| -3.0 | -9.0 | 1 | 0 | 1 | 0 | 1 |
| -1.5 | -7.5 | 1 | 0 | 1 | 1 | 0 |
| 0.0 | -6.0 | 1 | 0 | 1 | 1 | 1 |
| 1.5 | -4.5 | 1 | 1 | 0 | 0 | 0 |
| 3.0 | -3.0 | 1 | 1 | 0 | 0 | 1 |
| 4.5 | -1.5 | 1 | 1 | 0 | 1 | 0 |
| 6.0 | 0.0 | 1 | 1 | 0 | 1 | 1 |
| 7.5 | 1.5 | 1 | 1 | 1 | 0 | 0 |
| 9.0 | 3.0 | 1 | 1 | 1 | 0 | 1 |
| 10.5 | 4.5 | 1 | 1 | 1 | 1 | 0 |
| 12.0 | 6.0 | 1 | 1 | 1 | 1 | 1 |

### 2.3 SPI Timing Diagram



## 3 ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
| :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{CC}}$ | Supply voltage ${ }^{1}$ | 6 | V |
| $\mathrm{T}_{\text {oper }}$ | Operating Free Air Temperature Range | -40 to + 85 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {stg }}$ | Storage Temperature | -65 to +150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{j}}$ | Maximum Junction Temperature | 150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{R}_{\text {thja }}$ | Flip Chip Thermal Resistance Junction to Ambient ${ }^{2}$ | 166 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Pd | Power Dissipation | Internally Limited |  |
| ESD | Human Body Model ${ }^{3}$ | 2 | kV |
| ESD | Machine Model ${ }^{4}$ | 100 | V |
|  | Latch-up Immunity | 200 | mA |
|  | Lead Temperature (soldering, 10sec) | 250 | ${ }^{\circ} \mathrm{C}$ |

1) All voltage values are measured with respect to the ground pin.
2) Device is protected in case of over temperature by a thermal shutdown active @ $150^{\circ} \mathrm{C}$ typ.
3) Human body model, 100 pF discharged through a $1.5 \mathrm{k} \Omega$ resistor into pin of device.
4) This is a minimum Value. Machine model ESD, a 200pF cap is charged to the specified voltage, then discharged directly into the IC with no external series resistor (internal resistor $<5 \Omega$ ), into pin to pin of device.
5.) All PSRR data limits are guaranteed by evaluation tests.

## 4 OPERATING CONDITIONS

| Symbol | Parameter | Value | Unit |
| :---: | :--- | :---: | :---: |
| $\mathrm{V}_{\mathrm{CC}}$ | Supply Voltage | 3 to 5 | V |
| $\mathrm{~V}_{\text {phin }}$ | Maximum Phone In Input Voltage | $\mathrm{G}_{\mathrm{ND}}$ to $\mathrm{V}_{\mathrm{CC}}$ | V |
| $\mathrm{V}_{\text {Rin }} / \mathrm{V}_{\text {Lin }}$ | Maximum Rin \& Lin Input Voltage | $\mathrm{G}_{\mathrm{ND}}$ to $\mathrm{V}_{\mathrm{CC}}$ | V |
| $\mathrm{T}_{\mathrm{SD}}$ | Thermal Shutdown Temperature | 150 | ${ }^{\circ} \mathrm{C}$ |

## 5 ELECTRICAL CHARACTERISTICS

Table 4: Electrical characteristics at VCC $=+5.0 \mathrm{~V}, \mathrm{GND}=0 \mathrm{~V}, \mathrm{Tamb}=25^{\circ} \mathrm{C}$ (unless otherwise specified)

| Symbol | Parameter | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{I}_{\mathrm{Cc}}$ | Supply Current, all gain @ max settings <br> Output Mode 1, Vin $=0 \mathrm{~V}$, no load <br> Output Mode 1, Vin $=0 \mathrm{~V}$, loaded ( $8 \Omega$ ) <br> Output Mode 2,3,4,5,6,7 Vin $=0 \mathrm{~V}$, no loads <br> Output mode $2,3,4,5,6,7 \mathrm{Vin}=0 \mathrm{~V}$, loaded $(8 \Omega, 32 \Omega)$ |  | $\begin{aligned} & 4.0 \\ & 5.5 \\ & 8.0 \\ & 10 \end{aligned}$ | $\begin{gathered} 8 \\ 9 \\ 11 \\ 12 \end{gathered}$ | mA |
| $\mathrm{I}_{\text {Standby }}$ | Standby Current Output Mode 0 |  | 0.75 | 2 | $\mu \mathrm{A}$ |
| Voo | Output Offset Voltage (differential) <br> Output Mode 1 to 7, Vin = 0 V, no load, Speaker Out <br> Output Mode 2 to 7 Vin $=0 \mathrm{~V}$, no loads, Headset Out |  | $\begin{aligned} & 5 \\ & 5 \end{aligned}$ | $\begin{aligned} & 20 \\ & 40 \end{aligned}$ | mV |
| Vil | "Logic low" input Voltage | 0 |  | 0.4 | V |
| Vih | "Logic high" input Voltage | 1.4 |  | 5 | V |
| Po | Output Power $\begin{aligned} & \text { SPKR } \text { out }^{\text {R }} \text { RL }=8 \Omega, \mathrm{THD}+\mathrm{N}=1 \%, f=1 \mathrm{kHz} \\ & \mathrm{R}_{\text {out }} \& \mathrm{~L}_{\text {out }}, R L=32 \Omega, \mathrm{THD}+\mathrm{N}=0.5 \%, \mathrm{f}=1 \mathrm{kHz} \end{aligned}$ | $\begin{gathered} 800 \\ 70 \end{gathered}$ | $\begin{gathered} 1100 \\ 100 \end{gathered}$ |  | mW |
| THD + N | Total Harmonic Distortion + Noise <br> $\mathrm{R}_{\text {out }} \& \mathrm{~L}_{\text {out }}, \mathrm{Po}=70 \mathrm{~mW}, \mathrm{f}=1 \mathrm{kHz}, \mathrm{RL}=32 \Omega$ <br> SPKR $_{\text {out }}, \mathrm{Po}=800 \mathrm{~mW}, \mathrm{f}=1 \mathrm{kHz}, \mathrm{RL}=8 \Omega$ <br> $R_{\text {out }} \& L_{\text {out }}, \mathrm{Po}^{2}=50 \mathrm{~mW}, 20 \mathrm{~Hz}<\mathrm{f}<20 \mathrm{kHz}, R L=32 \Omega$ <br> $\mathrm{SPKR}_{\text {out }}, \mathrm{Po}=400 \mathrm{~mW}, 20 \mathrm{~Hz}<\mathrm{f}<20 \mathrm{kHz}, \mathrm{RL}=8 \Omega$ |  | $\begin{aligned} & 0.5 \\ & 0.5 \\ & 0.5 \end{aligned}$ | 1 | \% |
| SNR | Signal To Noise Ratio A-Weighted, $f=1 \mathrm{kHz}$ |  | 80 |  | dB |
| PSRR ${ }^{5)}$ | Power Supply Rejection Ratio <br> SPKR $_{\text {out }} ;$ Vripple $=200 \mathrm{mV}$ Vpp, $\mathrm{F}=217 \mathrm{~Hz}$, Input Terminated $50 \Omega$ <br> Gain $(B T L)=12 \mathrm{~dB}$, Output mode 1,3,5,7 <br> $\mathrm{R}_{\text {out }}$ \& $\mathrm{L}_{\text {out }}$ Vripple $=200 \mathrm{mV}$ Vpp, $\mathrm{F}=217 \mathrm{~Hz}$, Input Terminated $50 \Omega$ <br> Maximum gain setting, Output mode 2,3 <br> $\mathrm{R}_{\text {out }}$ \& $\mathrm{L}_{\text {out }}$ Vripple $=200 \mathrm{mV}$ Vpp, $F=217 \mathrm{~Hz}$, Input Terminated $50 \Omega$ <br> Maximum gain setting, Output mode 4,5 <br> $\mathrm{R}_{\text {out \& }} \mathrm{L}_{\text {out }}$ VVripple $=200 \mathrm{mV}$ Vpp, $F=217 \mathrm{~Hz}$, Input Terminated $50 \Omega$ <br> Maximum gain setting, Output mode 6,7 | 58 <br> 52 <br> 50 <br> 46 | 62 <br> 61 <br> 58 <br> 53 |  | dB |
| G2 | Digital Gain Range (Rin \& Lin) to $\mathrm{R}_{\text {out }}, \mathrm{L}_{\text {out }}$ | -34.5 |  | 12 | dB |
| G1 | Digital Gain Range (Phone In HS) to $\mathrm{R}_{\text {out }}$, $\mathrm{L}_{\text {out }}$ | -40.5 |  | 6 | dB |
|  | Digital Gain Stepsize |  | 1.5 |  | dB |
|  | Stepsize Error |  | $\pm 0.6$ |  | dB |

Table 4: Electrical characteristics at VCC $=+5.0 \mathrm{~V}, \mathrm{GND}=0 \mathrm{~V}$, Tamb $=25^{\circ} \mathrm{C}$ (unless otherwise specified)

| Symbol | Parameter | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | Phone In Volume <br> BTL maximum GAIN from Phone In HS to $\mathrm{R}_{\text {out }}, \mathrm{L}_{\text {out }}$ BTL minimum GAIN from Phone $\ln H S$ to $R_{\text {out }}$, $L_{\text {out }}$ | $\begin{gathered} 5.4 \\ -41.1 \end{gathered}$ | $\begin{gathered} 6 \\ -40.5 \end{gathered}$ | $\begin{gathered} 6.6 \\ -39.9 \end{gathered}$ | dB |
|  | Phone In Volume BTL maximum gain from Rin, Lin to $R_{\text {out }}$, $L_{\text {out }}$ BTL minimum gain from Rin, Lin to $R_{\text {out }}, L_{\text {out }}$ | $\begin{array}{r} 11.4 \\ -35.1 \end{array}$ | $\begin{gathered} 12 \\ -34.5 \end{gathered}$ | $\begin{gathered} 12.6 \\ -33.9 \end{gathered}$ | dB |
|  | Phone In Volume BTL gain from Phone In IHF to SPKR $_{\text {out }}$ | 11.4 | 12 | 12.6 | dB |
| Zin | Phone In IHF Input Impedance | 16 | 20 | 24 | $\mathrm{k} \Omega$ |
| Zin | Phone In HS, Rin \& Lin Input Impedance, All Gain setting | 42.5 | 50 | 57.5 | k $\Omega$ |
| tes | Enable Step up Time - ENB | 20 |  |  | ns |
| teh | Enable Hold Time - ENB | 20 |  |  | ns |
| tel | Enable Low Time - ENB | 30 |  |  | ns |
| tds | Data Setup Time- DATA | 20 |  |  | ns |
| tdh | Data Hold Time - DATA | 20 |  |  | ns |
| tcs | Clock Setup time - CLK | 20 |  |  | ns |
| tch | Clock Logic High Time - CLK | 50 |  |  | ns |
| tcl | Clock Logic Low Time - CLK | 50 |  |  | ns |
| fclk | Clock Frequency - CLK | DC |  | 10 | MHz |

Table 5: Electrical characteristics at VCC $=+3.0 \mathrm{~V}$, GND $=0 \mathrm{~V}$, Tamb $=25^{\circ} \mathrm{C}$ (unless otherwise specified)

| Symbol | Parameter | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{I}_{\mathrm{CC}}$ | Supply Current, all gain @ max settings <br> Output Mode 1, Vin $=0 \mathrm{~V}$, no load <br> Output Mode 1, Vin $=0$ V, loaded ( $8 \Omega$ ) <br> Output Mode $2,3,4,5,6,7$ Vin $=0 \mathrm{~V}$, no loads <br> Output mode $2,3,4,5,6,7 \mathrm{Vin}=0 \mathrm{~V}$, loaded $(8 \Omega, 32 \Omega)$ |  | $\begin{gathered} 3.5 \\ 4.5 \\ 7.5 \\ 9 \end{gathered}$ | $\begin{gathered} 7 \\ 8 \\ 10 \\ 11 \end{gathered}$ | mA |
| $\mathrm{I}_{\text {Standby }}$ | Standby Current Output Mode 0 |  | 0.6 | 2 | $\mu \mathrm{A}$ |
| Voo | Output Offset Voltage (differential) <br> Output Mode 1 to 7, Vin = 0 V, no load, Speaker Out <br> Output Mode 2 to 7 Vin $=0 \mathrm{~V}$, no loads, Headset Out |  | $\begin{aligned} & 5 \\ & 5 \end{aligned}$ | $\begin{aligned} & 20 \\ & 40 \end{aligned}$ | mV |
| Vil | "Logic low" input Voltage | 0 |  | 0.4 | V |
| Vih | "Logic high" input Voltage | 1.4 |  | 3 | V |

Table 5: Electrical characteristics at $\mathrm{VCC}=+3.0 \mathrm{~V}, \mathrm{GND}=0 \mathrm{~V}, \mathrm{Tamb}=25^{\circ} \mathrm{C}$ (unless otherwise specified)

| Symbol | Parameter | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Po | Output Power $\begin{aligned} & \mathrm{SPKR}_{\text {out }}, \mathrm{RL}=8 \Omega, \mathrm{THD}=1 \%, \mathrm{f}=1 \mathrm{kHz} \\ & \mathrm{R}_{\text {out }} \& \mathrm{~L}_{\text {out }}, \mathrm{RL}=32 \Omega, \mathrm{THD}=0.5 \%, \mathrm{f}=1 \mathrm{kHz} \end{aligned}$ | $\begin{gathered} 300 \\ 20 \end{gathered}$ | $\begin{gathered} 340 \\ 25 \end{gathered}$ |  | mW |
| THD + N | Total Harmonic Distortion + Noise <br> $R_{\text {out }} \& L_{\text {out }}, \mathrm{Po}=20 \mathrm{~mW}, \mathrm{f}=1 \mathrm{kHz}, \mathrm{RL}=32 \Omega$ <br> $\mathrm{SPKR}_{\text {out }}, \mathrm{Po}=300 \mathrm{~mW}, \mathrm{f}=1 \mathrm{kHz}, \mathrm{RL}=8 \Omega$ <br> $R_{\text {out }} \& L_{\text {out }}, \mathrm{Po}_{\mathrm{o}}=15 \mathrm{~mW}, 20 \mathrm{~Hz}<\mathrm{f}<20 \mathrm{kHz}, R \mathrm{R}=32 \Omega$ <br> SPKR $_{\text {out }}$, Po $=250 \mathrm{~mW}, 20 \mathrm{~Hz}<\mathrm{f}<20 \mathrm{kHz}, \mathrm{RL}=8 \Omega$ |  | $\begin{aligned} & 0.5 \\ & 0.5 \end{aligned}$ | $\begin{gathered} 0.5 \\ 1 \end{gathered}$ | \% |
| SNR | Signal To Noise Ratio A-Weighted, $\mathrm{f}=1 \mathrm{kHz}$ |  | 80 |  | dB |
| PSRR ${ }^{5)}$ | Power Supply Rejection Ratio SPKR $_{\text {out }}$,Vripple $=200 \mathrm{mV}$ Vpp, $\mathrm{F}=217 \mathrm{~Hz}$, Input Terminated $50 \Omega$ Gain $(B T L)=12 \mathrm{~dB}$, Output Mode 1,3,5,7 $R_{\text {out }} \& L_{\text {out }}$ Vripple $=200 \mathrm{mV}$ Vpp, $F=217 \mathrm{~Hz}$, Input Terminated $50 \Omega$ Maximum gain setting, Output Mode 2,3 $R_{\text {out }} \& L_{\text {out }}$ Vripple $=200 \mathrm{mV}$ Vpp, $F=217 \mathrm{~Hz}$, Input Terminated $50 \Omega$ Maximum gain setting, Output Mode 4,5 $R_{\text {out }} \& L_{\text {out }}$ Vripple $=200 \mathrm{mV}$ Vpp, $F=217 \mathrm{~Hz}$, Input Terminated $50 \Omega$ Maximum gain setting, Output Mode 6,7 | 58 <br> 52 <br> 49 <br> 45 | 62.5 <br> 56.5 <br> 55 <br> 49.5 |  | dB |
| G2 | Digital Gain Range - Rin \& Lin to $\mathrm{R}_{\text {out }}$, $\mathrm{L}_{\text {out }}$ | -34.5 |  | 12 | dB |
| G1 | Digital Gain Range - Phone In HS to $\mathrm{R}_{\text {out }}$, $\mathrm{L}_{\text {out }}$ | -40.5 |  | 6 | dB |
|  | Digital Gain stepsize |  | 1.5 |  | dB |
|  | Stepsize Error |  | $\pm 0.6$ |  | dB |
|  | Phone In Volume <br> BTL maximum GAIN from Phone In HS to $\mathrm{R}_{\text {out }}, \mathrm{L}_{\text {out }}$ BTL minimum GAIN from Phone $\ln H S$ to $R_{\text {out }}$, $L_{\text {out }}$ | $\begin{gathered} 5.4 \\ -41.1 \end{gathered}$ | $\begin{gathered} 6 \\ -40.5 \end{gathered}$ | $\begin{gathered} 6.6 \\ -39.9 \end{gathered}$ | dB |
|  | Phone In Volume BTL maximum gain from Rin, Lin to $R_{\text {out }}, L_{\text {out }}$ BTL minimum gain from Rin, Lin to $R_{\text {out }}, L_{\text {out }}$ | $\begin{gathered} 11.4 \\ -35.1 \end{gathered}$ | $\begin{gathered} 12 \\ -34.5 \end{gathered}$ | $\begin{array}{r} 12.6 \\ -33.9 \end{array}$ | dB |
|  | Phone In Volume BTL gain from Phone In IHF to SPKR $_{\text {out }}$ | 11.4 | 12 | 12.6 | dB |
| Zin | Phone In IHF Input Impedance, all gains setting | 16 | 20 | 24 | $\mathrm{k} \Omega$ |
| Zin | Phone In HS, Rin \& Lin Input Impedance, all gains setting | 42.5 | 50 | 57.5 | $\mathrm{k} \Omega$ |
| tes | Enable Step up Time - ENB | 20 |  |  | ns |
| teh | Enable Hold Time - ENB | 20 |  |  | ns |
| tel | Enable Low Time - ENB | 30 |  |  | ns |

Table 5: Electrical characteristics at VCC $=+3.0 \mathrm{~V}, \mathrm{GND}=0 \mathrm{~V}, \mathrm{Tamb}=25^{\circ} \mathrm{C}$ (unless otherwise specified)

| Symbol | Parameter | Min. | Typ. | Max. | Unit |
| :--- | :--- | :---: | :---: | :---: | :---: |
| tds | Data Setup Time- DATA | 20 |  |  | ns |
| tdh | Data Hold Time - DATA | 20 |  |  | ns |
| tcs | Clock Setup time - CLK | 20 |  |  | ns |
| tch | Clock Logic High Time - CLK | 50 |  |  | ns |
| tcl | Clock Logic Low Time - CLK | 50 |  |  | ns |
| fclk | Clock Frequency - CLK | DC |  | 10 | MHz |

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Note: In the graphs that follow, the abbreviations Spkout = Speaker Output, and HDout = Headphone Output are used.

Figure 1: Spkout THD+N vs. output power (Output modes 1, 3, 5, 7)


Figure 2: Spkout THD+N vs. output power (Output modes 1, 3, 5, 7)


Figure 3: Spkout THD+N vs. output power (Output modes 1, 3, 5, 7)


Figure 4: HDout THD+N vs. output power (Output modes 2, $3 \mathrm{G}=+6 \mathrm{~dB}$ )


Figure 5: HDout THD+N vs. output power (Output modes 2, $3 \mathrm{G}=+3 \mathrm{~dB}$ )


Figure 6: HDout THD+N vs. output power (Output modes 2, $3 \mathrm{G}=+6 \mathrm{~dB}$ )


Figure 7: HDout THD+N vs. output power (Output modes 2, $3 \mathrm{G}=+3 \mathrm{~dB}$ )


Figure 8: HDout THD+N vs. output power (Output modes 4, $5 \mathrm{G}=+12 \mathrm{~dB}$ )


Figure 9: HDout THD+N vs. output power (Output modes 4, $5 \mathrm{G}=+6 \mathrm{~dB}$ )


Figure 10: HDout THD+N vs. output power (Output modes 4, $5 \mathrm{G}=+12 \mathrm{~dB}$ )


Figure 11: HDout THD+N vs. output power (Output modes 4, $5 \mathrm{G}=+6 \mathrm{~dB}$ )


Figure 12: HDout THD+N vs. frequency (Output modes 1, 3, 5, 7)


Figure 13: Spkout THD+N vs. frequency (Output modes 1, 3, 5, 7)


Figure 14: Spout THD+N vs. frequency (Output modes 1, 3, 5, 7)


Figure 15: HDout THD+N vs. frequency (Output modes 2, $3 \mathrm{G}=+6 \mathrm{~dB}$ )


Figure 16: HDout THD+N vs. Frequency (Output modes 2, 3 G=+6dB)


Figure 17: HDout THD+N vs. frequency (Output modes $4,5 \mathrm{G}=+12 \mathrm{~dB}$ )


Figure 18: HDout THD+N vs. frequency (Output modes 4, $5 \mathrm{G}=+12 \mathrm{~dB}$ )


Figure 19: Speaker output power vs. power supply voltage (Output modes 1, 3, 5, 7)


Figure 20: Speaker output power vs. power supply voltage (Output modes $1,3,5,7$ )


Figure 21: Headphone output power vs. power supply voltage (Output modes 2, 3, 4, 5, 6, 7)


Figure 22: Headphone output power vs. power supply voltage (Output modes $2,3,4,5,6,7$ )


Figure 23: Speaker output power vs. load resistance (Output modes 1, 3, 5, 7)


Figure 24: Speaker output power vs. load resistance (Output modes 1, 3, 5, 7)


Figure 25: Headphone output power vs. load resistance (Output modes 2, 3, 4, 5, 6, 7)


Figure 26: Headphone output power vs. load resistance (Output modes 2, 3, 4, 5, 6, 7)


Figure 27: Spkout PSRR vs. frequency (Output modes 1, 3, 5, 7 input grounded)


Figure 28: Spkout PSRR vs. frequency (Output modes 2, 4, 6 input grounded)


Figure 29: HDout PSRR vs. frequency (Output modes 2, 3 input grounded)


Figure 30: HDout PSRR vs. frequency (Output modes 2, 3 input grounded)


Figure 31: HDout PSRR vs. frequency (Output modes 4, 5 inputs grounded)


Figure 32: HDout PSRR vs. frequency (Output modes 4, 5 inputs grounded)


Figure 33: HDout PSRR vs. frequency (Output modes 6, 7 inputs grounded)


Figure 34: HDout PSRR vs. frequency (Output modes 6, 7 inputs grounded)


Figure 35: Spkout mute attenuation vs. frequency (Output modes 2, 4, 6)


Figure 36: Spkout frequency response (Output modes 1, 3, 5, 7)


Figure 37: HDout frequency response (Output modes 2, $3 \mathrm{G}=+6 \mathrm{~dB}$ )


Figure 38: HDout frequency response (Output modes 4, $5 \mathrm{G}=+12 \mathrm{~dB}$ )


Figure 39: Spkout -3dB lower cut off freq. vs. input capacitor (Output modes 1, 3, 5, 7)


Figure 40: HDout -3dB lower cut-off frequency vs. input capacitor (Output modes 2, 3, 4, 5, 6, 7)


Figure 41: HDout -3dB lower cut-off freq. vs. gain setting (Output modes 2, 3, 4, 5, 6, 7)


Figure 42: Power derating curves


Figure 43: Spkout SNR vs. power supply voltage, unweighted filter, BW = 20 Hz to 20 kHz


Figure 44: Spkout SNR vs. power supply voltage, weighted filter A, BW = 20 Hz to 20 kHz


Figure 45: HDout SNR vs. power supply voltage, unweighted filter, BW= $\mathbf{2 0 ~ H z ~ t o ~} \mathbf{2 0} \mathbf{~ k H z}$


Figure 46: HDout SNR vs. power supply voltage, weighted filter $A, B W=\mathbf{2 0 H z}$ to $\mathbf{2 0 k H z}$


Figure 47: HDout SNR vs. Power supply voltage, unweighted filter, $B W=20 \mathrm{~Hz}$ to 20 kHz


Figure 48: HDout SNR vs. power supply voltage, weighted filter A, BW = 20 Hz to 20 kHz


Figure 49: HDout SNR vs. power supply voltage, unweighted filter, BW = $\mathbf{2 0 ~ H z}$ to $\mathbf{2 0 ~ k H z ) ~}$


Figure 50: HDout SNR vs. power supply voltage, weighted filter A, BW = 20 Hz to 20 kHz )


Figure 51: Current consumption vs. power supply voltage


Figure 52: Power dissipation vs. output power: speaker output


Figure 53: Power dissipation vs. output power: speaker output


Figure 54: Power dissipation vs. output power. headphone output one channel


Figure 55: Power dissipation vs. output power. headphone output one channel


## 6 APPLICATION INFORMATION

### 6.1 BTL Configuration Principle

The TS4855 integrates 3 monolithic power amplifiers having BTL output. BTL (Bridge Tied Load) means that each end of the load is connected to two single-ended output amplifiers. Thus, we have:

Single ended output $1=$ Vout1 $=$ Vout (V)
Single ended output $2=$ Vout2 $=-\operatorname{Vout}(\mathrm{V})$
and
Vout1 - Vout2 = 2Vout (V)

The output power is:

$$
\text { Pout }=\frac{\left(2 \text { Vout }_{\mathrm{RMS}}\right)^{2}}{\mathrm{R}_{\mathrm{L}}}(\mathrm{~W})
$$

For the same power supply voltage, the output power in BTL configuration is 4 times higher than the output power in single-ended configuration.

### 6.2 Power dissipation and efficiency

Hypotheses:

- Voltage and current in the load are sinusoidal (Vout and lout).
- Supply voltage is a pure DC source (Vcc).

Regarding the load we have:

$$
\text { VOUT }=\mathrm{V}_{\text {PEAK }} \sin \omega t(\mathrm{~V})
$$

and

$$
\text { IOUT }=\frac{\text { VOUT }}{R L}(A)
$$

and

$$
\text { POUT }=\frac{\text { VPEAK }^{2}}{2 R L}(\mathrm{~W})
$$

Therefore, the average current delivered by the supply voltage is:

$$
I_{A V G}=2 \frac{V P E A K}{\pi R L}(A)
$$

The power delivered by the supply voltage is:

$$
\text { Psupply = Vcc } \mathrm{Icc}_{\mathrm{AVG}}(\mathrm{~W})
$$

Then, the power dissipated by each amplifier is Pdiss = Psupply - Pout (W)

$$
\begin{equation*}
\mathrm{P}_{\text {diss }}=\frac{2 \sqrt{2} \mathrm{~V}_{\mathrm{CC}}}{\pi \sqrt{\mathrm{R}_{\mathrm{L}}}} \sqrt{\mathrm{P}_{\mathrm{OUT}}}-\mathrm{P}_{\mathrm{OUT}} \tag{W}
\end{equation*}
$$

and the maximum value is obtained when:

$$
\frac{\partial \mathrm{Pdiss}}{\partial \mathrm{PoUT}}=0
$$

and its value is:

$$
\text { Pdissmax }=\frac{2 \mathrm{Vcc}^{2}}{\pi^{2} \mathrm{R}_{\mathrm{L}}}(\mathrm{~W})
$$

Note: This maximum value is only depending on power supply voltage and load values.

The efficiency is the ratio between the output power and the power supply

$$
\eta=\frac{\text { Pout }}{\text { Psupply }}=\frac{\pi \mathrm{V} \text { PEAK }}{4 \mathrm{Vcc}}
$$

The maximum theoretical value is reached when Vpeak = Vcc, so

$$
\frac{\pi}{4}=78.5 \%
$$

The TS4855 has 3 independent power amplifiers and each amplifier produces heat due to its power dissipation. Therefore, the maximum die temperature is the sum of the each amplifier's maximum power dissipation. It is calculated as follows:
$\mathrm{P}_{\text {diss speaker }}=$ Power dissipation due to the speaker power amplifier.
$P_{\text {diss head }}=$ Power dissipation due to each headphone's power amplifier.
Total $P_{\text {diss }}=P_{\text {diss speaker }}+P_{\text {diss head1 }}+P_{\text {diss head2 }}(W)$ In most cases, $\mathrm{P}_{\text {diss head1 }}=\mathrm{P}_{\text {diss head 2 }}$, giving:

Total $P_{\text {diss }}=P_{\text {diss speaker }}+2 P_{\text {diss head }}(W)$
TotalP $_{\text {diss }}=\frac{2 \sqrt{2} \mathrm{~V}_{\text {CC }}}{\pi}\left[\sqrt{\frac{\mathrm{P}_{\text {OUT SPEAKER }}}{\mathrm{R}_{\text {LSPEAKER }}}}+2 \sqrt{\frac{\mathrm{P}_{\text {OUT HEAD }}}{\mathrm{R}_{\text {LHEAD }}}}\right]$

$$
-\left[\mathrm{P}_{\text {OUT SPEAKER }}+2 \mathrm{P}_{\text {OUT HEAD }}\right] \quad(\mathrm{W})
$$

The following graph shows an example of the previous formula, with Vcc set to +5 V , $\mathrm{R}_{\text {load speaker }}$ set to $8 \Omega$, and $\mathrm{R}_{\text {load headphone }}$ se to $16 \Omega$.

Figure 56: Example of total power dissipation vs. speaker and headphone output power


### 6.3 Low frequency response

In low frequency region, the effect of Cin starts. Cin with Zin forms a high pass filter with a -3 dB cut off frequency.

$$
\mathrm{F}_{\mathrm{CL}}=\frac{1}{2 \pi \mathrm{Zin} \operatorname{Cin}}(\mathrm{~Hz})
$$

Zin is the input impedance of the corresponding input:

- $20 \mathrm{k} \Omega$ for Phone In IHF input
- $50 \mathrm{k} \Omega$ for the 3 other inputs

Note: For all inputs, the impedance value remains constant for all gain settings. This means that the lower cut-off frequency doesn't change with gain setting. Note also that $20 \mathrm{k} \Omega$ and $50 \mathrm{k} \Omega$ are typical values and there are tolerances around these values (see Electrical Characteristics on page 6).

In Figures 39 to 41, you could easily establish the Cin value for a -3 dB cut-off frequency required.

### 6.4 Decoupling of the circuit

Two capacitors are needed to bypass properly the TS4855, a power supply bypass capacitor Cs and a bias voltage bypass capacitor Cb.

Cs has especially an influence on the THD +N in high frequency (above 7 kHz ) and indirectly on the power supply disturbances.
With $1 \mu \mathrm{~F}$, you could expect similar THD+N performances like shown in the datasheet.
If Cs is lower than $1 \mu \mathrm{~F}, \mathrm{THD}+\mathrm{N}$ increases in high frequency and disturbances on the power supply rail are less filtered.

To the contrary, if Cs is higher than $1 \mu \mathrm{~F}$, those disturbances on the power supply rail are more filtered.
$\mathbf{C b}$ has an influence on $\mathrm{THD}+\mathrm{N}$ in lower frequency, but its value is critical on the final result of PSRR with input grounded in lower frequency:

- If Cb is lower than $1 \mu \mathrm{~F}, \mathrm{THD}+\mathrm{N}$ increases at lower frequencies and the PSRR worsens upwards.
- If Cb is higher than $1 \mu \mathrm{~F}$, the benefit on THD+N and PSRR in the lower frequency range is small.


### 6.5 Startup time

When the TS4855 is controlled to switch from the full standby mode (output mode 0 ) to another output mode, a delay is necessary to stabilize the DC bias. This delay depends on the Cb value and can be calculated by the following formulas.

Typical startup time $=0.0175 \times \mathrm{Cb}(\mathrm{s})$
Max. startup time $=0.025 \times \mathrm{Cb}(\mathrm{s})$
( Cb is in $\mu \mathrm{F}$ in these formulas)
These formulas assume that the Cb voltage is equal to 0 V . If the Cb voltage is not equal to 0 V , the startup time will be always lower.
The startup time is the delay between the negative edge of Enable input (see SPI Operation Description on page 3) and the power ON of the output amplifiers.
Note: When the TS4855 is set in full standby mode, Cb is discharged through an internal switch. The time to reach $0 V$ of $C b$ voltage with $1 \mu F$ is about 1 ms .

### 6.6 Pop and Click performance

The TS4855 has internal Pop and Click reduction circuitry. The performance of this circuitry is closely linked with the value of the input capacitor Cin and the bias voltage bypass capacitor Cb .

The value of Cin is due to the lower cut-off frequency value requested. The value of Cb is due to $\mathrm{THD}+\mathrm{N}$ and PSRR requested always in lower frequency.

The TS4855 is optimized to have a low pop and click in the typical schematic configuration (see page 2).

Note: The value of Cs is not an important consideration as regards pop and click.

### 6.7 Notes on PSRR measurement

## What is the PSRR?

The PSRR is the Power Supply Rejection Ratio. The PSRR of a device, is the ratio between a power supply disturbance and the result on the output. We can say that the PSRR is the ability of a device to minimize the impact of power supply disturbances to the output.

## How we measure the PSRR?

The PSSR was measured according to the schematic shown in Figure 57.

Figure 57: PSRR measurement schematic


## Principles of operation

- The DC voltage supply (Vcc) is fixed.
- The AC sinusoidal ripple voltage (Vripple) is fixed.
- No bypass capacitor Cs is used.

The PSRR value for each frequency is:

$$
\operatorname{PSRR}=20 \times \log \left[\frac{R \mathrm{RS}_{\text {(Output ) }}}{\operatorname{RMS}}{ }_{\text {(Vripple ) }}\right] \quad(\mathrm{dB})
$$

Note: The measure of the Rms voltage is a Rms selective measure with a bandpass equal to $1 \%$ of the measured frequency .

### 6.8 Power-On Reset

When Power is applied to Vdd, an internal Power On Reset holds the TS4855 in a reset state until the Supply Voltage reached its nominal value. The Power On reset has a typical threshold at 1.8 V .

Figure 58: TS4855 Footprint Recommendation


## 7 PACKAGE INFORMATION

Flip-chip package-18 bumps: TS4855IJT

Marking (on top view)

Part number: B55
Three digit Datecode: YWW
The dot is for marking the bump1A

Package mechanical data


Pin out (top view)


## Daisy chain mechanical data

All drawings dimensions are in millimeters


## Remarks

Daisy chain sample is featuring pin connection two by two. The schematic above is illustrating the way connecting pins each others. This sample is used for testing continuity on board. PCB needs to be designed on the opposite way, where pin connections are not done on daisy chain samples. By that way, just connecting a Ohmmeter between pin 1A and pin 5A, the soldering process continuity can be tested.

Order code

| Part Number | Temperature Range | Package | Marking |
| :---: | :---: | :---: | :---: |
|  |  | J |  |
| TSDC02IJT | $-40,+85^{\circ} \mathrm{C}$ | - | DC2 |

## 8 TAPE \& REEL SPECIFICATION

Figure 59: Top view of tape \& reel


## Device orientation

The devices are oriented in the carrier pocket with bump number A1 adjacent to the sprocket holes.


#### Abstract

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